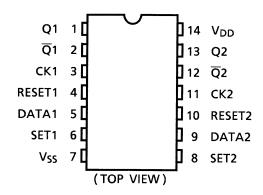
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC4013BP,TC4013BF,TC4013BFN

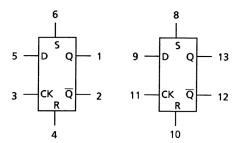
TC4013B Dual D-Type Flip Flop

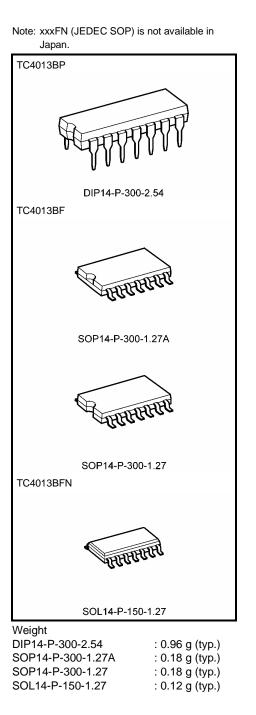
TC4013B contains two independent circuits of D type flip-flop. The input level applied to DATA input are transferred to Q and  $\overline{Q}$  output by rising edge of the clock pulse. When SET input is placed at "H", and RESET input is placed at "L", outputs become Q = "H", and  $\overline{Q} =$  "L". When RESET input is placed at "H", and SET input is placed at "L", outputs become Q = "H". When both of RESET input and SET input are at "H", outputs become Q = "H".

#### **Pin Assignment**



#### **Block Diagram**





# TOSHIBA

# Truth Table

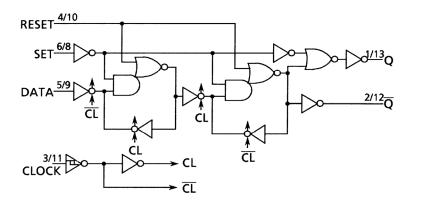
	Inp	Outputs				
RESET	SET	DATA CKA		Qn + 1	$\overline{Q}n+1$	
L	Н	*	*	н	L	
н	L	*	*	L	н	
н	Н	*	*	Н	Н	
L	L	L		L	Н	
L	L	н		Н	L	
L	L	*	$\overline{}$	Qn <sup>.</sup>	Qn '	

\*: Don't care

 $\Delta$ : Level change

·: No change

#### Logic Diagram



#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
DC supply voltage	V <sub>DD</sub>	$V_{SS}-0.5V_{SS}+20$	V
Input voltage	V <sub>IN</sub>	$V_{SS}-0.5\text{-}V_{DD}+0.5$	V
Output voltage	V <sub>OUT</sub>	$V_{SS}-0.5V_{DD}+0.5$	V
DC input current	I <sub>IN</sub>	±10	mA
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T <sub>opr</sub>	-40~85	°C
Storage temperature range	T <sub>stg</sub>	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

# Recommended Operating Conditions (V<sub>SS</sub> = 0 V) (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
DC supply voltage	V <sub>DD</sub>	_	3	_	18	V
Input voltage	V <sub>IN</sub>	_	0	_	V <sub>DD</sub>	V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Static Electrical Characteristics (V<sub>SS</sub> = 0 V)

Characteristics Symbol		Svm-	Test Condition	-40°C		25°C			85°C			
				V <sub>DD</sub> (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit
			I <sub>OUT</sub>   < 1 μΑ	5	4.95	_	4.95	5.00	_	4.95	_	
High-level output voltage	VOH	10		9.95	—	9.95	10.00	_	9.95	_	V	
· · · · · · · · · · · · · · · · · · ·			$V_{IN} = V_{SS},  V_{DD}$	15	14.95	_	14.95	15.00	_	14.95	_	
			I <sub>OUT</sub>   < 1 μΑ	5	_	0.05	_	0.00	0.05		0.05	
Low-level voltage	output	V <sub>OL</sub>		10	_	0.05	_	0.00	0.05	—	0.05	V
			$V_{IN} = V_{SS}, V_{DD}$	15	_	0.05	—	0.00	0.05	—	0.05	
			$V_{OH} = 4.6 V$	5	-0.61	_	-0.51	-1.0	_	-0.42	_	mA
			$V_{OH} = 2.5 V$	5	-2.50	_	-2.10	-4.0	_	-1.70	_	
Output hig	h current	IOH	$V_{OH} = 9.5 V$	10	-1.50	_	-1.30	-2.2	_	-1.10	_	
			V <sub>OH</sub> = 13.5 V	15	-4.00	—	-3.40	-9.0	_	-2.80	_	
			$V_{IN} = V_{SS}, \ V_{DD}$									
			$V_{OL} = 0.4 V$	5	0.61	_	0.51	1.2	_	0.42	_	mA
Output lov	ourropt		$V_{OL} = 0.5 \ V$	10	1.50	—	1.30	3.2	_	1.10	_	
Output low current	I <sub>OL</sub>	$V_{OL} = 1.5 \ V$	15	4.00	_	3.40	12.0	_	2.80	_	ША	
			$V_{IN} = V_{SS}, \ V_{DD}$									
		VIH	$V_{OUT} = 0.5 V, 4.5 V$	5	3.5	_	3.5	2.75	_	3.50	_	V
lanut biada	veltere		$V_{OUT} = 1.0 V, 9.0 V$	10	7.0	—	7.0	5.50	_	7.00	_	
Input high	voitage		$V_{OUT} = 1.5 V, 13.5 V$	15	11.0	—	11.0	8.25	_	11.00	_	
			I <sub>OUT</sub>   < 1 μA									
			$V_{OUT} = 0.5 V, 4.5 V$	5		1.5		2.25	1.5		1.5	
In most large			$V_{OUT} = 1.0 V, 9.0 V$	10	—	3.0	_	4.50	3.0		3.0	
Input low voltage	VIL	$V_{OUT} = 1.5 V, 13.5 V$	15	—	4.0	_	6.75	4.0		4.0	V	
			$ I_{OUT}  < 1 \ \mu A$									
Input current	"H" level	IIH	V <sub>IH</sub> = 18 V	18	_	0.1	_	10 <sup>-5</sup>	0.1	_	1.0	
	"L" level	١ <sub>١L</sub>	$V_{IL} = 0 V$	18	_	-0.1		-10 <sup>-5</sup>	-0.1		-1.0	μA
Quiescent supply current				5		1		0.002	1	_	30	
		I <sub>DD</sub>	$V_{IN} = V_{SS}, V_{DD}$	10	—	2		0.004	2		60	μA
			(Note)	15	—	4	—	0.008	4		120	

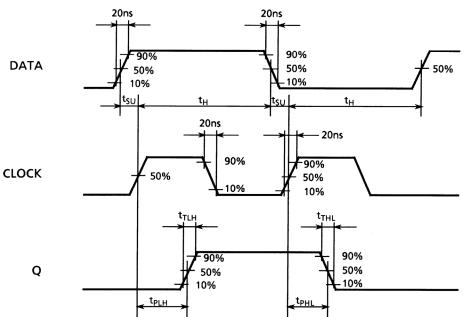
Note: All valid input combinations.

# Dynamic Electrical Characteristics (Ta = 25°C, $V_{SS}$ = 0 V, $C_L$ = 50 pF)

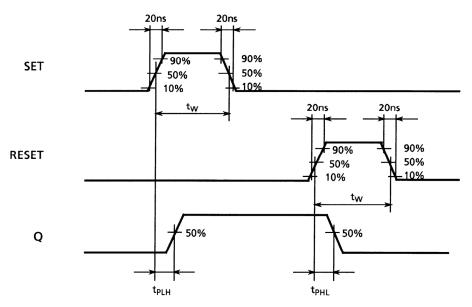
Characteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Characteristics	Gymbol		V <sub>DD</sub> (V)	IVIIII	тур.		
Output transition time			5	—	70	200	
(low to high)	tTLH	_	10	—	35	100	ns
			15	_	30	80	
Output transition time			5	—	70	200	
(high to low)	t <sub>THL</sub>	—	10	—	35	100	ns
			15	_	30	80	
Propagation delay time	+		5	—	130	300	
$(CK-Q, \overline{Q})$	t <sub>pLH</sub>	_	10	—	65	130	ns
(01-0, 0)	<sup>t</sup> pHL		15	_	50	90	
Propagation delay time			5	_	110	300	
(SET, RESET-Q, $\overline{Q}$ )	<sup>t</sup> pLH	—	10	—	50	130	ns
(SET, RESET-Q, Q)			15	_	40	90	
Propagation delay time			5	_	110	300	
(SET, RESET-Q, $\overline{Q}$ )	t <sub>pHL</sub>	—	10	—	50	130	ns
(SEI, RESEI-Q, Q)			15	—	40	90	
			5	3.5	8	_	
Max clock frequency	f <sub>CL</sub>	_	10	8.0	16		MHz
			15	12.0	20		
Manual and the disc		_	5	No limit			μs
Max clock input rise time	t <sub>rCL</sub>		10				
Max clock input fall time	tfCL		15				
Min mode a suiddle	t <sub>W</sub>		5	_	60	180	ns
Min pulse width		_	10	_	30	80	
(SET, RESET)			15	_	25	50	
			5	_	60	140	
Min clock pulse width	tw	_	10	_	30	60	ns
			15	—	25	40	
Min and sup time.			5			40	
Min set-up time	t <sub>su</sub>	_	10	_	_	20	ns
(DATA-CK)			15	_		15	
			5	_	20	40	
Min hold time	t <sub>H</sub>	_	10	_	10	20	ns
(DATA-CK)			15	_	6	15	
<b>N</b> <sup>2</sup> 1.2			5	_		40	1
Min removal time	t <sub>rem</sub>	_	10	_	_	20	ns
(SET, RESET-CK)			15			15	
Input capacitance	C <sub>IN</sub>	_			5	7.5	pF

## Waveform for Measurement of Dynamic Characteristics





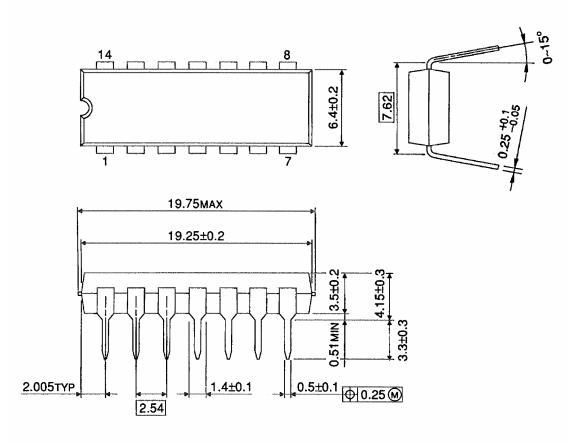
Waveform 2



## Package Dimensions

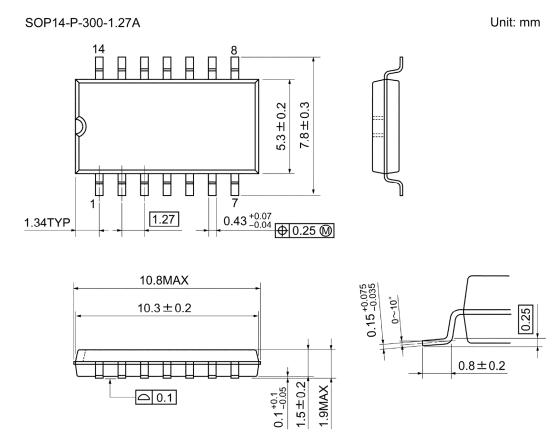
DIP14-P-300-2.54

Unit : mm



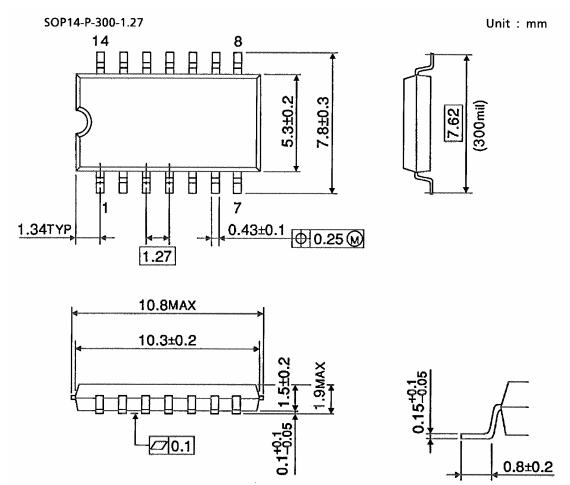
Weight: 0.96 g (typ.)

#### **Package Dimensions**



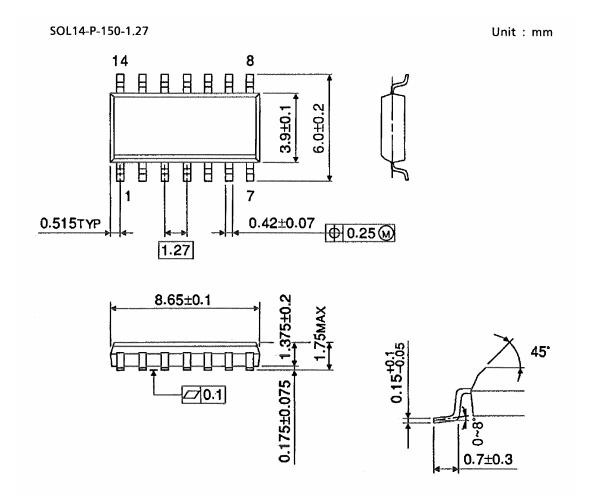
Weight: 0.18 g (typ.)

# Package Dimensions



Weight: 0.18 g (typ.)

## Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27

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